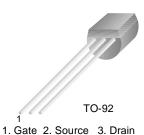


# **N-Channel RF Amplifier**

- This device is designed for HF/VHF mixer/amplifier and applications where process 50is not adequate. Sufficient gain and low noise for sensitive receivers.
- Sourced from process 90.



# Absolute Maximum Ratings\* Ta=25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V <sub>DG</sub>	Drain-Gate Voltage	30	V
√ <sub>GS</sub>	Gate-Source Voltage	-30	V
GF	Forward Gate Current	10	mA
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	-55 ~ 150	°C

\* This ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### NOTES:

1) These rating are based on a maximum junction temperature of 150 degrees C.
2) These are steady limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

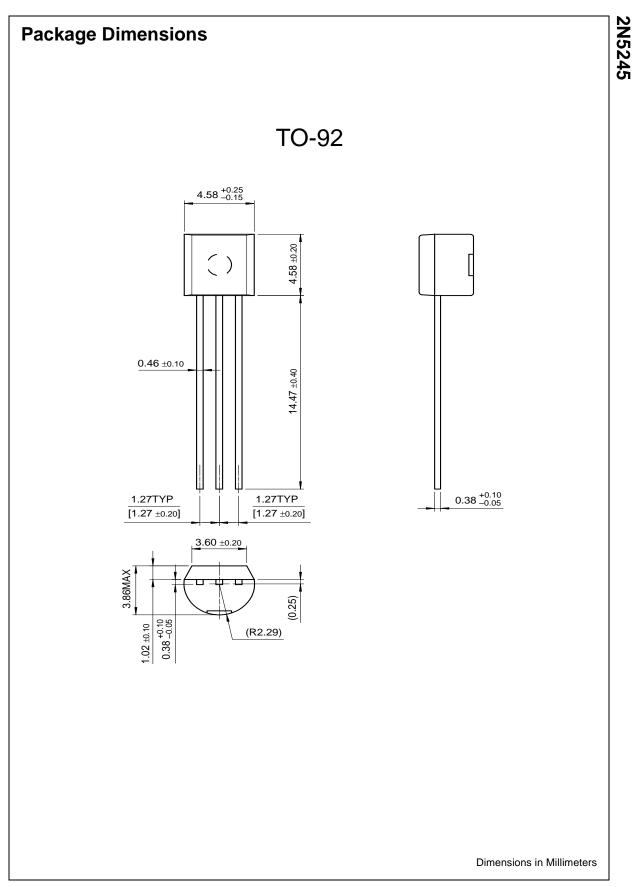
## Electrical Characteristics T<sub>a</sub>=25°C unless otherwise noted

Parameter	Test Condition	Min.	Max.	Units
teristics				
Gate-Source Breakdwon Voltage	$I_{G} = 1.0 \mu A, V_{DS} = 0$	-30		V
Gate Reverse Current	$V_{GS} = 25V, V_{DS} = 0$		-1.0	nA
Gate-Source Cutoff Voltage	V <sub>DS</sub> = 15V, I <sub>D</sub> = 1.0nA	-1.0	-0.6	V
teristics				
Zero-Gate Voltage Drain Current *	$V_{DS} = 15V, V_{GS} = 0$	5	15	mA
al Characteristics				
Forward Transferconductance	$V_{GS} = 0V, V_{DS} = 15V, f = 1.0kHz$	4500	11000	μmhos
Common- Source Output Conductance	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 15V, f = 1.0kHz		50	μmhos
	teristics Gate-Source Breakdwon Voltage Gate Reverse Current Gate-Source Cutoff Voltage teristics Zero-Gate Voltage Drain Current * al Characteristics Forward Transferconductance	teristics         Gate-Source Breakdwon Voltage $I_G = 1.0\mu A, V_{DS} = 0$ Gate Reverse Current $V_{GS} = 25V, V_{DS} = 0$ Gate-Source Cutoff Voltage $V_{DS} = 15V, I_D = 1.0nA$ teristics       Zero-Gate Voltage Drain Current *         VDS = 15V, VGS = 0       Nal Characteristics         Forward Transferconductance $V_{GS} = 0V, V_{DS} = 15V, f = 1.0kHz$	teristicsGate-Source Breakdwon Voltage $I_G = 1.0\mu A$ , $V_{DS} = 0$ -30Gate Reverse Current $V_{GS} = 25V$ , $V_{DS} = 0$ -30Gate-Source Cutoff Voltage $V_{DS} = 15V$ , $I_D = 1.0nA$ -1.0teristics2ero-Gate Voltage Drain Current * $V_{DS} = 15V$ , $V_{GS} = 0$ 5al CharacteristicsForward Transferconductance $V_{GS} = 0V$ , $V_{DS} = 15V$ , $f = 1.0kHz$ 4500	teristicsGate-Source Breakdwon Voltage $I_G = 1.0\mu A, V_{DS} = 0$ -30Gate Reverse Current $V_{GS} = 25V, V_{DS} = 0$ -1.0Gate-Source Cutoff Voltage $V_{DS} = 15V, I_D = 1.0nA$ -1.0Gate-Source Cutoff Voltage $V_{DS} = 15V, I_D = 1.0nA$ -1.0teristicsZero-Gate Voltage Drain Current * $V_{DS} = 15V, V_{GS} = 0$ 515 cal CharacteristicsForward Transferconductance $V_{GS} = 0V, V_{DS} = 15V, f = 1.0kHz$ 450011000

Pulse Test: Pulse  $\leq 300 \mu s$ 

# Thermal Characteristics T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Max.	Units
PD	Total Device Dissipation	350	mW
	Derate above 25°C	2.8	mW/°C
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case	125	°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient	357	°C/W



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Programmable A	ctive Droop™	POP™	SuperFET™	

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### PRODUCT STATUS DEFINITIONS

#### **Definition of Terms**

Datasheet Identification	Product Status	Definition
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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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